# Dual supply configurable multiple function gate Rev. 5 — 3 July 2017 Pr

**Product data sheet** 

#### **General description** 1

The 74AXP1T57 is a dual supply configurable multiple function gate with Schmitt-trigger inputs. It features three inputs (A, B and C), an output (Y) and dual supply pins (V<sub>CCI</sub> and  $V_{CCO}$ ). The inputs are referenced to  $V_{CCI}$  and the output is referenced to  $V_{CCO}$ . All inputs can be connected directly to  $V_{CCI}$  or GND.  $V_{CCI}$  can be supplied at any voltage between 0.7 V and 2.75 V and  $V_{CCO}$  can be supplied at any voltage between 1.2 V and 5.5 V. This feature allows voltage level translation. The 74AXP1T57 can be configured as any of the following logic functions AND, OR, NAND, NOR, XNOR, inverter and buffer.

This device ensures very low static and dynamic power consumption across the entire supply range and is fully specified for partial power down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

#### Features and benefits 2

- · Wide supply voltage range:
  - V<sub>CCI</sub>: 0.7 V to 2.75 V
  - V<sub>CCO</sub>: 1.2 V to 5.5 V
- Low input capacitance; C<sub>I</sub> = 0.6 pF (typical)
- Low output capacitance; C<sub>O</sub> = 1.8 pF (typical)
- Low dynamic power consumption; C<sub>PD</sub> = 0.6 pF at V<sub>CCI</sub> = 1.2 V (typical)
- Low dynamic power consumption; C<sub>PD</sub> = 7.1 pF at V<sub>CCO</sub> = 3.3 V (typical)
- Low static power consumption; I<sub>CCI</sub> = 0.5 μA (85 °C maximum)
- Low static power consumption; I<sub>CCO</sub> = 1.8 μA (85 °C maximum)
- High noise immunity
- Complies with JEDEC standard:
  - JESD8-12A.01 (1.1 V to 1.3 V; A, B, C inputs)
  - JESD8-11A.01 (1.4 V to 1.6 V)
  - JESD8-7A (1.65 V to 1.95 V)
  - JESD8-5A.01 (2.3 V to 2.7 V)
  - JESD8-C (2.7 V to 3.6 V; Y output)
  - JESD12-6 (4.5 V to 5.5 V; Y output)
- ESD protection:
  - HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 2 kV
  - CDM JESD22-C101E exceeds 1000 V
- Latch-up performance exceeds 100 mA per JESD78D Class II
- Inputs accept voltages up to 2.75 V
- Low noise overshoot and undershoot < 10 % of V<sub>CCO</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- Multiple package options



• Specified from -40 °C to +85 °C

# 3 Ordering information

**Table 1. Ordering information** 

Type number	Package								
	Temperature range	Name	Description	Version					
74AXP1T57DC	-40 °C to +85 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1					
74AXP1T57GT	-40 °C to +85 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm	SOT833-1					
74AXP1T57GN	-40 °C to +85 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm	SOT1116					
74AXP1T57GS	-40 °C to +85 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm	SOT1203					
74AXP1T57GX	-40 °C to +85 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 x 0.8 x 0.35 mm	SOT1233					

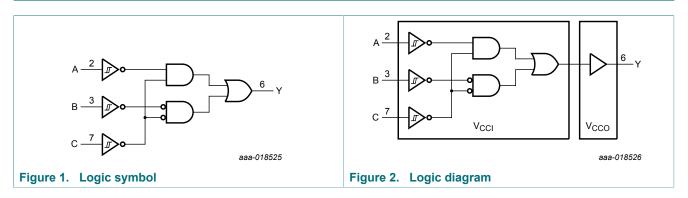
## 4 Marking

Table 2. Marking

Table 2. Marking	
Type number	Marking code <sup>[1]</sup>
74AXP1T57DC	rD
74AXP1T57GT	rD
74AXP1T57GN	rD
74AXP1T57GS	rD
74AXP1T57GX	rD

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5 Functional diagram



74AXP1T57

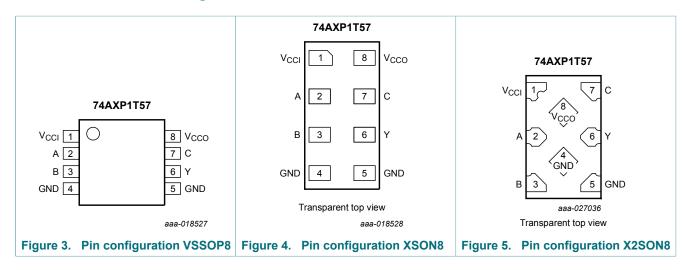
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## 6 Pinning information

## 6.1 Pinning



## 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
V <sub>CCI</sub>	1	input supply voltage
A, B, C	2, 3, 7	data input
GND [1]	4, 5	ground (0 V)
Υ	6	data output
V <sub>CCO</sub>	8	output supply voltage

<sup>[1]</sup> All GND pins must be connected to ground (0 V).

# 7 Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care; \ Z = high-impedance \ OFF-state.$ 

Supply voltage		Input	Output		
V <sub>CCI</sub>	V <sub>cco</sub>	С	В	A	Υ
0.7 V to 2.75 V	1.2 V to 5.5 V	L	L	L	Н
0.7 V to 2.75 V	1.2 V to 5.5 V	L	L	Н	L
0.7 V to 2.75 V	1.2 V to 5.5 V	L	Н	L	Н
0.7 V to 2.75 V	1.2 V to 5.5 V	L	Н	Н	L
0.7 V to 2.75 V	1.2 V to 5.5 V	Н	L	L	L
0.7 V to 2.75 V	1.2 V to 5.5 V	Н	L	Н	L
0.7 V to 2.75 V	1.2 V to 5.5 V	Н	Н	L	Н
0.7 V to 2.75 V	1.2 V to 5.5 V	Н	Н	Н	Н
GND	1.2 V to 5.5 V	Х	Х	Х	Z
0.7 V to 2.75 V	GND	Х	Х	Х	Z
GND	GND	Х	Х	Х	Z

# 7.1 Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input AND	see Figure 6
2-input AND with both inputs inverted	see Figure 9
2-input NAND with inverted input	see Figure 7 and Figure 8
2-input OR with inverted input	see Figure 7 and Figure 8
2-input NOR	see Figure 9
2-input NOR with both inputs inverted	see Figure 6
2-input XNOR	see Figure 10
Inverter	see Figure 11
Buffer	see Figure 12

#### Dual supply configurable multiple function gate

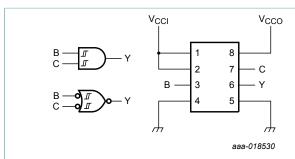


Figure 6. 2-input AND gate or 2-input NOR gate with both inputs inverted

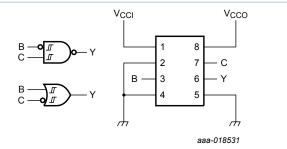


Figure 7. 2-input NAND gate with input B inverted or 2input OR gate with inverted C input

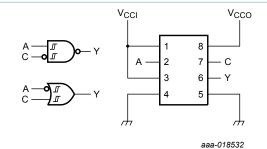


Figure 8. 2-input NAND gate with input C inverted or 2input OR gate with inverted A input

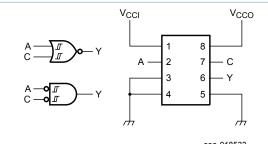
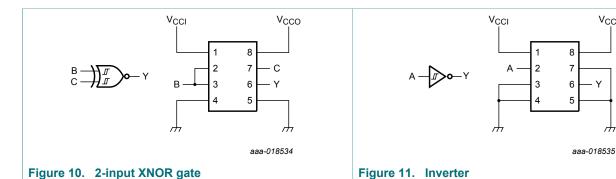
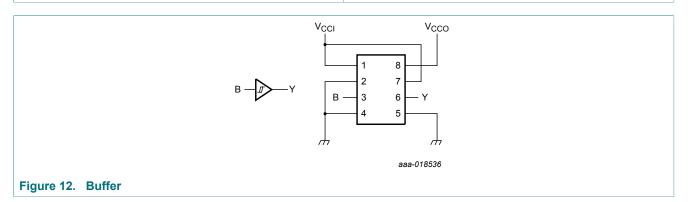


Figure 9. 2-input NOR gate or 2-input AND gate with both inputs inverted





 $V_{\text{CCO}}$ 

Dual supply configurable multiple function gate

## 8 Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CCI</sub>	input supply voltage			-0.5	+3.3	V
V <sub>CCO</sub>	output supply voltage			-0.5	+6.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+3.3	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
Vo	output voltage	Active mode	[1] [2]	-0.5	V <sub>CCO</sub> + 0.5	V
		Power-down or 3-state mode	[1]	-0.5	+6.0	V
Io	output current	$V_O = 0 V \text{ to } V_{CCO}$		-	±25	mA
I <sub>CCI</sub>	input supply current			-	50	mA
I <sub>CCO</sub>	output supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +85 °C	[3]	-	300	mW

<sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9 Recommended operating conditions

#### Table 7. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CCI</sub>	input supply voltage		0.7	2.75	V
V <sub>CCO</sub>	output supply voltage		1.2	5.5	V
VI	input voltage		0	2.75	V
Vo	output voltage	Active mode	0	$V_{CCO}$	V
		Power-down or 3-state mode	0	5.5	V
T <sub>amb</sub>	ambient temperature		-40	+85	°C

<sup>[2]</sup>  $V_{CCO} + 0.5 \text{ V}$  should not exceed 6.0 V.

<sup>[3]</sup> For SOT833-1 package: above 70 °C the value of P<sub>tot</sub> derates linearly with 3.2 mW/K. For SOT1203 package: above 80 °C the value of P<sub>tot</sub> derates linearly with 3.6 mW/K.

## 10 Static characteristics

**Table 8. Static characteristics** 

At recommended operating conditions, unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		T <sub>amb</sub> = -40	°C to +85 °	С	Unit
			Min	Typ 25 °C	Max 25 °C	Max 85 °C	
V <sub>T+</sub>	positive-going	see Figure 13 and Figure 14					
	threshold voltage	V <sub>CCI</sub> = 0.75 V to 0.85 V	0.3V <sub>CCI</sub>	-	0.8V <sub>CCI</sub>	0.8V <sub>CCI</sub>	V
		V <sub>CCI</sub> = 1.1 V to 1.95 V	0.4V <sub>CCI</sub>	-	0.7V <sub>CCI</sub>	0.7V <sub>CCI</sub>	V
		V <sub>CCI</sub> = 2.3 V to 2.7 V	0.9	-	1.7	1.7	V
V <sub>T-</sub>	negative-going	see Figure 13 and Figure 14					
	threshold voltage	V <sub>CCI</sub> = 0.75 V to 0.85 V	0.2V <sub>CCI</sub>	-	0.7V <sub>CCI</sub>	0.7V <sub>CCI</sub>	V
	voitage	V <sub>CCI</sub> = 1.1 V to 1.95 V	0.3V <sub>CCI</sub>	-	0.6V <sub>CCI</sub>	0.6V <sub>CCI</sub>	V
		V <sub>CCI</sub> = 2.3 V to 2.7 V	0.7	-	1.5	1.5	V
V <sub>H</sub>	hysteresis	see Figure 13 and Figure 14					
·n	voltage	V <sub>CCI</sub> = 0.75 V to 0.85 V	0.06V <sub>CCI</sub>	-	0.5V <sub>CCI</sub>	0.5V <sub>CCI</sub>	V
		V <sub>CCI</sub> = 1.1 V to 1.95 V	0.1V <sub>CCI</sub>	-	0.4V <sub>CCI</sub>	0.4V <sub>CCI</sub>	V
		V <sub>CCI</sub> = 2.3 V to 2.7 V	0.2	-	1.0	1.0	V
V <sub>OH</sub>	HIGH-level output voltage	$I_O = -2 \text{ mA}; V_{CCO} = 1.2 \text{ V}$	_	1.05	-	-	V
		I <sub>O</sub> = -3 mA; V <sub>CCO</sub> = 1.4 V	1.05	-	-	-	V
		I <sub>O</sub> = -4.5 mA; V <sub>CCO</sub> = 1.65 V	1.2	-	-	-	V
		I <sub>O</sub> = -8 mA; V <sub>CCO</sub> = 2.3 V	1.7	-	-	-	V
		$I_O = -10 \text{ mA}; V_{CCO} = 3.0 \text{ V}$	2.2	-	-	-	V
		$I_O = -12 \text{ mA}; V_{CCO} = 4.5 \text{ V}$	3.7	-	-	-	V
$V_{OL}$	LOW-level	$I_O = 2 \text{ mA}; V_{CCO} = 1.2 \text{ V}$	·] _	0.18	-	-	V
	output voltage	I <sub>O</sub> = 3 mA; V <sub>CCO</sub> = 1.4 V	-	-	0.35	0.35	V
	voitage	I <sub>O</sub> = 4.5 mA; V <sub>CCO</sub> = 1.65 V	-	-	0.45	0.45	V
		I <sub>O</sub> = 8 mA; V <sub>CCO</sub> = 2.3 V	-	-	0.7	0.7	V
		I <sub>O</sub> = 10 mA; V <sub>CCO</sub> = 3.0 V	-	-	0.8	0.8	V
		I <sub>O</sub> = 12 mA; V <sub>CCO</sub> = 4.5 V	-	-	0.8	0.8	V
lı	input leakage current	V <sub>I</sub> = 0 V to 2.75 V; V <sub>CCI</sub> = 0 V to 2.75 V	-	±0.001	±0.1	±0.5	μΑ
l <sub>OZ</sub>	OFF-state output current	V <sub>O</sub> = 0 V to 5.5 V; V <sub>CCO</sub> = 1.2 V to 5.5 V	-	±0.001	±0.1	±0.5	μΑ

## **Dual supply configurable multiple function gate**

Symbol	Parameter	Conditions			T <sub>amb</sub> = -40	<sub>mb</sub> = -40 °C to +85 °C			
				Min	Typ 25 °C	Max 25 °C	Max 85 °C		
I <sub>OFF</sub>	power-off leakage	inputs; V <sub>I</sub> = 0 V to 2.75 V; V <sub>CCI</sub> = 0 V; V <sub>CCO</sub> = 0 V to 5.5 V	[1]	-	±0.01	±0.1	±0.5	μΑ	
current	current	output; $V_O = 0 \text{ V to } 5.5 \text{ V};$ $V_{CCO} = 0 \text{ V}; V_{CCI} = 0 \text{ V to } 2.75 \text{ V};$ $V_I = 0 \text{ V to } 2.75 \text{ V}$	[1]	-	±0.01	±0.1	±0.5	μА	
ΔI <sub>OFF</sub>	additional power-off leakage	inputs; V <sub>I</sub> = 0 V or 2.75 V; V <sub>CCI</sub> = 0 V to 0.1 V; V <sub>CCO</sub> = 0 V to 5.5 V	[1]	-	±0.02	±0.1	±0.5	μА	
	current	output; $V_O = 0 \text{ V or } 5.5 \text{ V};$ $V_{CCO} = 0 \text{ V to } 0.1 \text{ V};$ $V_{CCI} = 0 \text{ V to } 2.75 \text{ V};$ $V_I = 0 \text{ V or } 2.75 \text{ V}$	[1]	-	±0.02	±0.1	±0.5	μА	

[1] Typical values are measured at  $V_{CCI} = V_{CCO} = 1.2 \text{ V}$  unless otherwise specified.

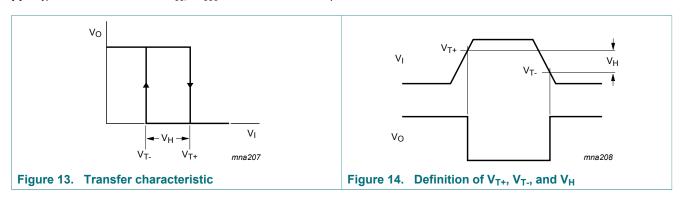


Table 9. Static characteristics supply current

At recommended operating conditions, unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	$T_{amb}$ = -40 °C to +85 °C				
			Typ 25 °C	Max 25 °C	Typ 85 °C	Max 85 °C	
I <sub>CCI</sub>	input supply	$V_I = 0 \text{ V or } V_{CCI};$					
	current	V <sub>CCI</sub> = 0.7 V to 1.3 V <sup>[1]</sup>	1	100	10	300	nA
		V <sub>CCI</sub> = 1.3 V to 2.75 V <sup>[2]</sup>	1	100	20	500	nA
		V <sub>CCI</sub> = 2.75 V; V <sub>CCO</sub> = 0 V	1	100	20	500	nA
		V <sub>CCI</sub> = 0 V; V <sub>CCO</sub> = 5.5 V	1	100	1	100	nA
I <sub>cco</sub>	output supply current	$V_I = 0 \text{ V or } V_{CCI}; I_O = 0 \text{ A};$ see <u>Table 10</u>					
		V <sub>CCO</sub> = 1.2 V to 3.6 V [1]	0.001	1.0	0.01	1.2	μΑ
		V <sub>CCO</sub> = 3.6 V to 5.5 V [3]	0.8	1.5	1.0	1.8	μΑ
		V <sub>CCI</sub> = 2.75 V; V <sub>CCO</sub> = 0 V	0.001	0.1	0.003	0.2	μΑ
		V <sub>CCI</sub> = 0 V; V <sub>CCO</sub> = 3.6 V	0.2	0.6	0.3	0.8	μΑ
		V <sub>CCI</sub> = 0 V; V <sub>CCO</sub> = 5.5 V	0.4	0.8	0.5	1.0	μΑ
Δl <sub>CCI</sub>	additional input supply current	V <sub>I</sub> = V <sub>CCI</sub> - 0.5 V; V <sub>CCI</sub> = 2.5 V	2	100	14	150	μΑ

Typical values are measured at  $V_{\rm CCI}$  =  $V_{\rm CCO}$  = 1.2 V unless otherwise specified. Typical values are measured at  $V_{\rm CCI}$  =  $V_{\rm CCO}$  = 2.5 V. Typical values are measured at  $V_{\rm CCI}$  = 1.2 V and  $V_{\rm CCO}$  = 5.0 V.

Table 10. Typical output supply current (I<sub>CCO</sub>)

V <sub>CCI</sub>		V <sub>cco</sub>								
	0 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V			
0 V	0	1	5	20	100	200	400	nA		
0.8 V	1	10	150	200	300	500	800	nA		
1.2 V	1	1	5	200	300	500	800	nA		
1.5 V	1	1	5	100	300	500	800	nA		
1.8 V	1	1	5	100	300	500	800	nA		
2.5 V	1	1	5	100	100	500	800	nA		

# 11 Dynamic characteristics

#### **Table 11. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 22; for waveform, see Figure 15.

Symbol	Parameter	arameter Conditions		V <sub>cco</sub>						
			1.2 V	1.2 V 1.5 \		V	1.8	1.8 V ± 0.15 V		
			Typ <sup>[1]</sup>	Min	Typ <sup>[1]</sup>	Max	Min	Typ <sup>[1]</sup>	Max	
$T_{amb} = 25$	°C									
t <sub>pd</sub>	propagation	A, B and C to Y								
	delay	V <sub>CCI</sub> = 0.75 V to 0.85 V	25	4	20	76	4	18	72	ns
		V <sub>CCI</sub> = 1.1 V to 1.3 V	16.5	3.4	10.9	21.0	3.0	8.9	17.0	ns
		V <sub>CCI</sub> = 1.4 V to 1.6 V	15.5	3.1	9.9	19.0	2.6	7.9	14.0	ns
		V <sub>CCI</sub> = 1.65 V to 1.95 V	15.0	2.6	9.4	18.0	2.1	7.4	12.5	ns
		V <sub>CCI</sub> = 2.3 V to 2.7 V	14.5	2.7	8.9	17.5	2.2	6.9	11.7	ns
$T_{amb} = -40$	0 °C to +85 °C	<b>;</b>								
t <sub>pd</sub>	propagation	A, B and C to Y								
	delay	V <sub>CCI</sub> = 0.75 V to 0.85 V	25	3	20	151	3	18	148	ns
		V <sub>CCI</sub> = 1.1 V to 1.3 V	16.5	3.4	10.9	21.0	3.0	8.9	17.0	ns
		V <sub>CCI</sub> = 1.4 V to 1.6 V	15.5	3.1	9.9	19.0	2.6	7.9	14.0	ns
		V <sub>CCI</sub> = 1.65 V to 1.95 V	15.0	2.6	9.4	18.0	2.1	7.4	12.5	ns
		V <sub>CCI</sub> = 2.3 V to 2.7 V	14.5	2.7	8.9	17.5	2.2	6.9	11.7	ns
t <sub>t</sub>	transition time	V <sub>CCI</sub> = 0.75 V to 2.7 V [3]	-	1.0	-	-	1.0	-	-	ns

Typical values are measured at nominal supply voltages and T<sub>amb</sub> = +25 °C.  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}.$   $t_{t}$  is the same as  $t_{THL}$  and  $t_{TLH}.$ 

Table 12. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 22; for waveform, see Figure 15.

Symbol	Parameter	Conditions	V <sub>cco</sub>						Unit			
			2.5 V ± 0.2 V 3.3 V			3 V ± 0.	/ ± 0.3 V 5		.0 V ± 0.5 V			
			Min	Typ <sup>[1]</sup>	Max	Min	Typ <sup>[1]</sup>	Max	Min	Typ <sup>[1]</sup>	Max	
T <sub>amb</sub> = 25	°C											
t <sub>pd</sub>	propagation	A, B and C to Y [2]										
	delay	V <sub>CCI</sub> = 0.75 V to 0.85 V	3	16	72	3	16	80	3	17	92	ns
		V <sub>CCI</sub> = 1.1 V to 1.3 V	2.6	7.3	12.0	2.5	6.7	10.7	2.4	6.4	10.2	ns
		V <sub>CCI</sub> = 1.4 V to 1.6 V	2.3	6.2	9.9	2.1	5.6	9.0	2.1	5.3	8.5	ns
		V <sub>CCI</sub> = 1.65 V to 1.95 V	1.7	5.7	9.3	1.6	5.1	8.3	1.5	4.8	7.9	ns
		V <sub>CCI</sub> = 2.3 V to 2.7 V	1.9	5.2	8.7	1.8	4.6	7.7	1.7	4.3	7.2	ns
T <sub>amb</sub> = -40	0 °C to +85 °C						<u>'</u>		'			
t <sub>pd</sub>	propagation delay	A, B and C to Y [2]										
		V <sub>CCI</sub> = 0.75 V to 0.85 V	2	16	167	2	16	194	2	17	225	ns
		V <sub>CCI</sub> = 1.1 V to 1.3 V	2.6	7.3	12.0	2.5	6.7	10.7	2.4	6.4	10.2	ns
		V <sub>CCI</sub> = 1.4 V to 1.6 V	2.3	6.2	9.9	2.1	5.6	9.0	2.1	5.3	8.5	ns
		V <sub>CCI</sub> = 1.65 V to 1.95 V	1.7	5.7	9.3	1.6	5.1	8.3	1.5	4.8	7.9	ns
		V <sub>CCI</sub> = 2.3 V to 2.7 V	1.9	5.2	8.7	1.8	4.6	7.7	1.7	4.3	7.2	ns
t <sub>t</sub>	transition time	$V_{CCI} = 0.75 \text{ V to } 2.7 \text{ V}$ [3]	1.0	-	-	1.0	-	-	1.0	-	-	ns

Typical values are measured at nominal supply voltages and  $t_{amb}$  = +25  $^{\circ}$ C.

 $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

#### Dual supply configurable multiple function gate

Table 13. Typical dynamic characteristics at T<sub>amb</sub> = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 22; for waveform, see Figure 15.

Symbol	Parameter	Conditions		V <sub>cco</sub>					Unit
				1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
C <sub>PD</sub>	power dissipation capacitance	$f_i$ = 1 MHz; $R_L$ = $\infty$ $\Omega$ ; $V_I$ = 0 V to $V_{CCI}$ [1]							
		input supply [2]							
		V <sub>CCI</sub> = 0.8 V	0.5	0.5	0.5	0.5	0.5	0.5	pF
		V <sub>CCI</sub> = 1.2 V	0.6	0.6	0.6	0.6	0.6	0.6	pF
		V <sub>CCI</sub> = 1.5 V	0.7	0.7	0.7	0.7	0.7	0.7	pF
		V <sub>CCI</sub> = 1.8 V	0.8	0.8	0.8	8.0	0.8	8.0	pF
		V <sub>CCI</sub> = 2.5 V	1.0	1.0	1.0	1.0	1.0	1.0	pF
		output supply [3]							
		V <sub>CCI</sub> = 0.8 V	6.7	6.8	6.8	6.9	7.5	9.5	pF
		V <sub>CCI</sub> = 1.2 V	6.8	6.9	7.0	7.0	7.1	7.6	pF
		V <sub>CCI</sub> = 1.5 V	6.9	6.9	6.9	7.0	7.1	7.6	pF
		V <sub>CCI</sub> = 1.8 V	6.9	6.9	6.9	7.0	7.2	7.6	pF
		V <sub>CCI</sub> = 2.5 V	6.9	7.0	7.0	7.0	7.2	7.6	pF
C <sub>I</sub>	input capacitance	$V_I = 0 \text{ V or } V_{CCI}$ ; $V_{CCI} = 0 \text{ V to } 2.7 \text{ V}$	0.6	0.6	0.6	0.6	0.6	0.6	pF
Co	output capacitance	V <sub>O</sub> = 0 V; V <sub>CCO</sub> = 0 V	1.8	1.8	1.8	1.8	1.8	1.8	pF

<sup>[1]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W). [2] Power dissipated from input supply ( $V_{CCI}$ )

 $P_D = C_{PD} \times V_{CCl}^2 \times f_i \times N$  where:  $C_{PD} = power dissipation capacitance of the input supply.$ 

V<sub>CCI</sub> = input supply voltage in V;

 $f_i$  = input frequency in MHz;

N = number of inputs switching;

[3] Power dissipated from output supply (V<sub>CCO</sub>)

 $P_D = (C_L + C_{PD}) \times V_{CCO}^2 \times f_o$  where:

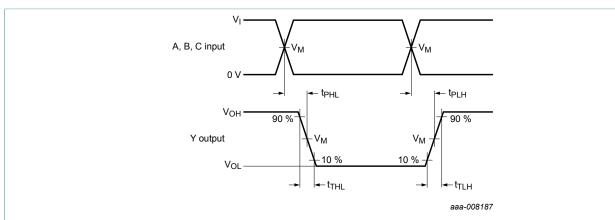
C<sub>L</sub> = load capacitance in pF;

C<sub>PD</sub> = power dissipation capacitance of the output supply.

 $V_{CCO}$  = output supply voltage in V;

fo = output frequency in MHz;

#### 11.1 Waveforms and graphs



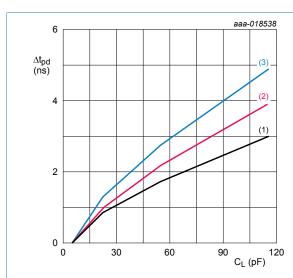
Measurement points are given in Table 14.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Figure 15. Input A, B and C to output Y propagation delay times and output transition times

**Table 14. Measurement points** 

Supply voltage		Output	Input		
V <sub>CCI</sub>	V <sub>CCO</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	
0.75 V to 2.7 V	1.2 V to 5.5 V	0.5V <sub>CCO</sub>	0.5V <sub>CCI</sub>	V <sub>CCI</sub>	



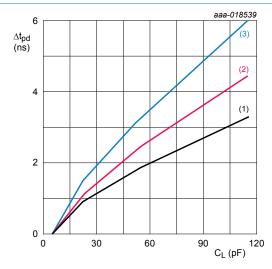
 $T_{amb}$  = -40 °C to +85 °C unless otherwise specified.

(1) Minimum:  $V_{CCO} = 5.5 \text{ V}$ 

(2) Typical:  $T_{amb} = 25 \,^{\circ}\text{C}$ ;  $V_{CCO} = 5 \,^{\circ}\text{V}$ 

(3) Maximum:  $V_{CCO} = 4.5 \text{ V}$ 

Figure 16. Additional propagation delay versus load capacitance



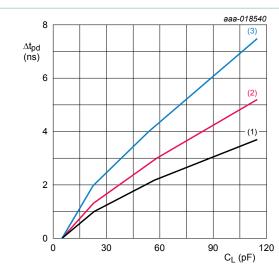
 $T_{amb}$  = -40 °C to +85 °C unless otherwise specified.

(1) Minimum: V<sub>CCO</sub> = 3.6 V

(2) Typical:  $T_{amb}$  = 25 °C;  $V_{CCO}$  = 3.3 V

(3) Maximum:  $V_{CCO} = 3 V$ 

Figure 17. Additional propagation delay versus load capacitance



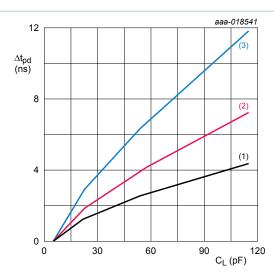
 $T_{amb}$  = -40 °C to +85 °C unless otherwise specified.

(1) Minimum:  $V_{CCO} = 2.7 \text{ V}$ 

(2) Typical:  $T_{amb}$  = 25 °C;  $V_{CCO}$  = 2.5 V

(3) Maximum:  $V_{CCO} = 2.3 \text{ V}$ 

Figure 18. Additional propagation delay versus load capacitance



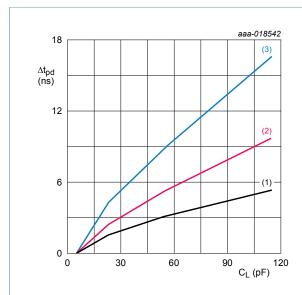
 $T_{amb}$  = -40 °C to +85 °C unless otherwise specified.

(1) Minimum:  $V_{CCO} = 1.95 \text{ V}$ 

(2) Typical:  $T_{amb}$  = 25 °C;  $V_{CCO}$  = 1.8 V

(3) Maximum:  $V_{CCO} = 1.65 \text{ V}$ 

Figure 19. Additional propagation delay versus load capacitance



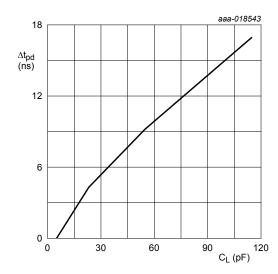
 $T_{amb}$  = -40 °C to +85 °C unless otherwise specified.

(1) Minimum:  $V_{CCO} = 1.6 \text{ V}$ 

(2) Typical:  $T_{amb}$  = 25 °C;  $V_{CCO}$  = 1.5 V

(3) Maximum:  $V_{CCO} = 1.4 \text{ V}$ 

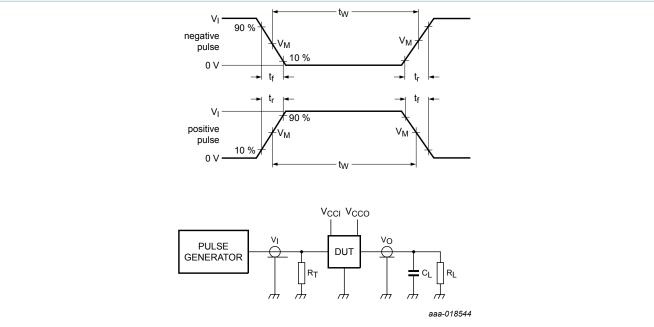
Figure 20. Additional propagation delay versus load capacitance



 $T_{amb} = 25 \, ^{\circ}C; \, V_{CCO} = 1.2 \, V.$ 

Figure 21. Additional propagation delay versus load capacitance

#### Dual supply configurable multiple function gate



Test data is given in Table 15.

Definitions test circuit:

 $R_T$  = termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $C_L$  = load capacitance including jig and probe capacitance.

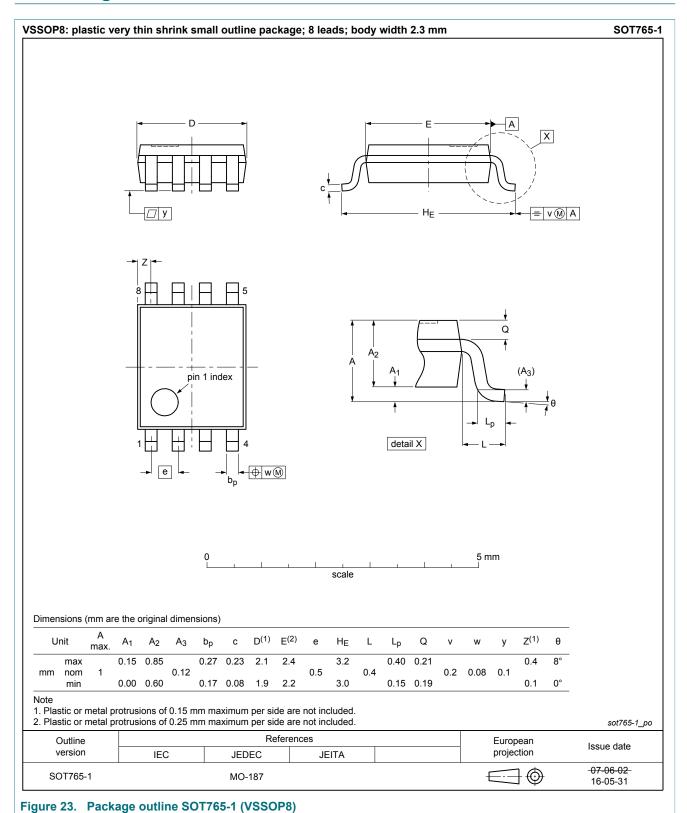
R<sub>L</sub> = Load resistance.

Figure 22. Test circuit for measuring switching times

Table 15. Test data

Supply voltage		Load		Input	
V <sub>CCI</sub>	V <sub>CCO</sub>	CL	R <sub>L</sub>	t <sub>r</sub> , t <sub>f</sub>	VI
0.75 V to 2.7 V	1.2 V to 5.5 V	5 pF	5 kΩ	≤3.0 ns	V <sub>CCI</sub>

## 12 Package outline



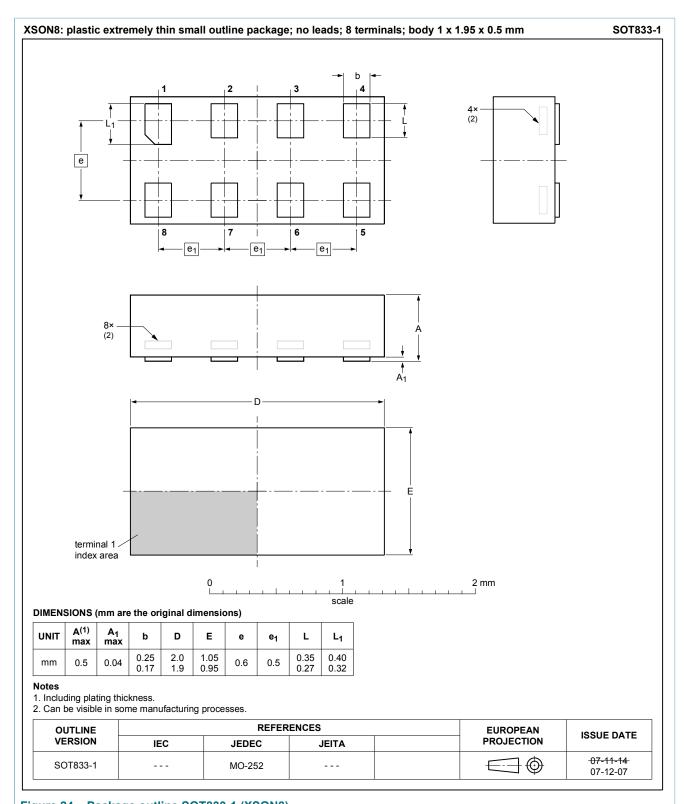


Figure 24. Package outline SOT833-1 (XSON8)

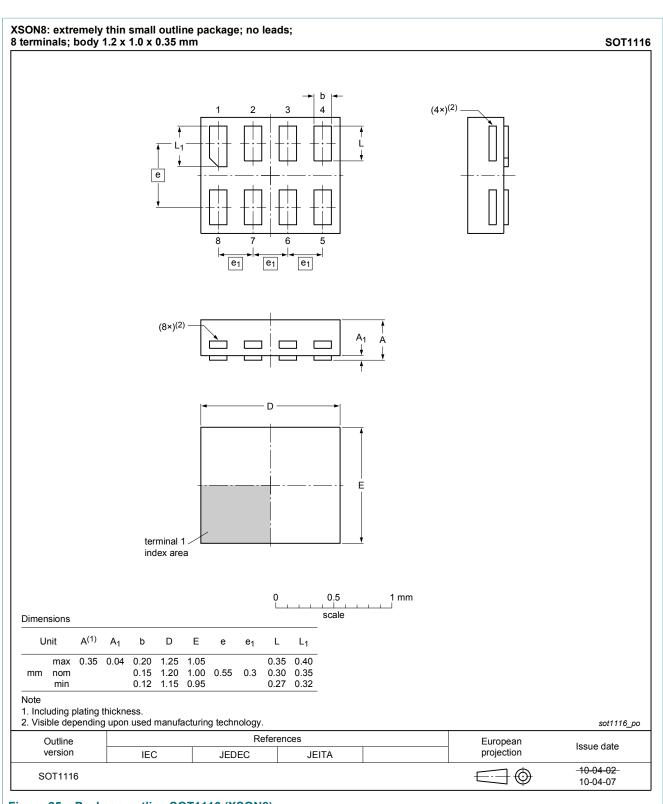


Figure 25. Package outline SOT1116 (XSON8)

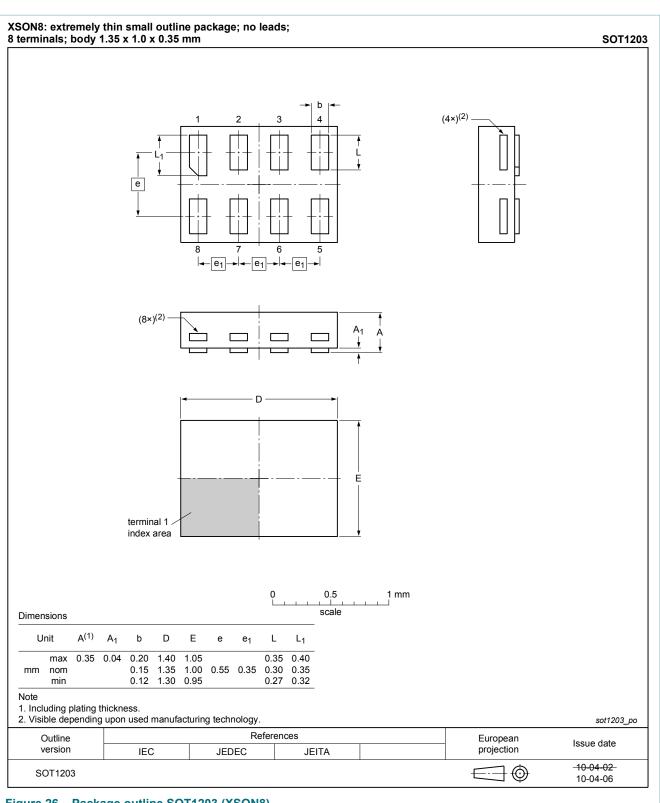


Figure 26. Package outline SOT1203 (XSON8)

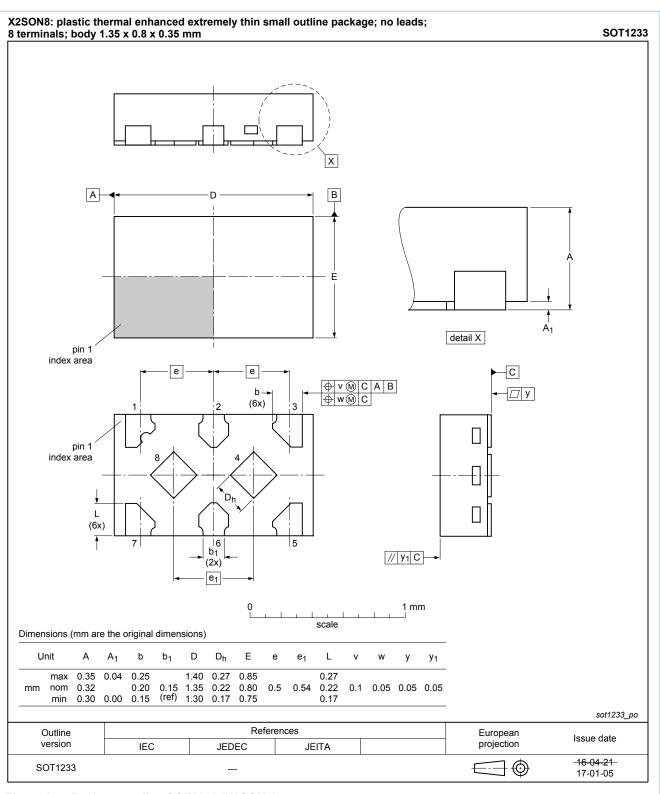


Figure 27. Package outline SOT1233 (X2SON8)

**Dual supply configurable multiple function gate** 

## 13 Abbreviations

#### **Table 16. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

# 14 Revision history

#### Table 17. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AXP1T57 v.5	20170703	Product data sheet	-	74AXP1T57 v.4			
Modifications:	Figure 27: Package outline drawing for SOT1233 / X2SON8) has changed.						
74AXP1T57 v.4	20161028	Product data sheet	-	74AXP1T57 v.3			
Modifications:	Added type num	ber 74AXP1T57GX (SOT123	3/X2SON8)				
74AXP1T57 v.3	20161007	Product data sheet	-	74AXP1T57 v.2			
Modifications:	Type numbers 7-	4AXP1T57DP and 74AXP1T5	7GD removed.				
74AXP1T57 v.2	20151222	Product data sheet	-	74AXP1T57 v.1			
Modifications:	<ul> <li>Table 6: Derating</li> <li>Table 7: Condition</li> <li>Table 8: Condition</li> <li>Table 9: Condition</li> <li>Table 11 and Tame</li> <li>Table 11: Condition</li> </ul>	ons $V_O$ corrected (errata). In a values for packages added (ons $V_O$ corrected (errata). In a $I_{OZ}$ corrected (errata). In a $I_{OZ}$ corrected (errata). In a $I_{CCI}$ corrected (errata). In a $I_{T}$ corrected (errata). In a $I_{T}$ corrected (errata). In a corrected (errata). In a corrected (errata). In a corrected (errata).	d (errata).				
74AXP1T57 v.1	20150803	Product data sheet	-	-			

## 15 Legal information

#### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions".
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### Dual supply configurable multiple function gate

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